

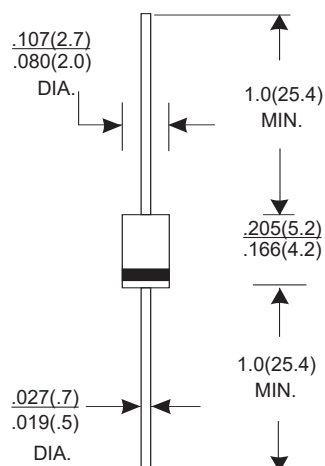
DO-41 Ultra-Fast Recovery Rectifier Diodes

FEATURES

- Low cost
- Diffused junction
- Low leakage
- Low forward voltage drop
- High current capability
- Easily cleaned with alcohol, Isopropanol and similar solvents

MECHANICAL DATA

- Case: JEDEC DO-41, molded plastic
- Terminals: Axial lead, solderable per MIL-STD-202, Method 208
- Polarity: Color band denotes cathode
- Weight: 0.012 ounces, 0.34 grams
- Mounting position: Any



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND CHARACTERISTICS

@ 25°C Ambient Temperature (unless otherwise noted)

Parameter	Symbol	BYV26A	BYV26B	BYV26C	BYV26D	BYV26E	UNITS
Maximum recurrent peak reverse voltage	V _{RRM}	200	400	600	800	1000	V
Maximum RMS voltage	V _{RMS}	140	280	420	560	700	V
Maximum DC blocking voltage	V _{DC}	200	400	600	800	1000	V
Maximum average forward rectified current 9.5 mm lead length, @T _A =75°C	I _{F(AV)}	1.0					A
Peak forward surge current 10ms single half-sine-wave superimposed on rated load @T _J =125°C	I _{FSM}	30.0					A
Maximum instantaneous forward voltage @ 1.0A	V _F	2.5					V
Maximum reverse current @T _A =25°C at rated DC blocking voltage @T _A =100°C	I _R	5.0 150.0					μA
Maximum reverse recovery time (Note1)	t _{rr}	30			75		ns
Typical junction capacitance (Note2)	C _J	45			40		pF
Typical thermal resistance (Note3)	R _{θJA}	100					°C/W
Operating junction temperature range	T _J	- 55 ----- + 150					°C
Storage temperature range	T _{STG}	- 55 ----- + 150					°C

NOTE: 1. Measured with $I_F = 0.5\text{A}$, $I_R = 1\text{A}$, $t_{rr} = 0.25\text{A}$.

2. Measured at 1MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance from junction to ambient.

RATINGS AND CHARACTERISTIC CURVES

FIG.1 – FORWARD DERATING CURVE

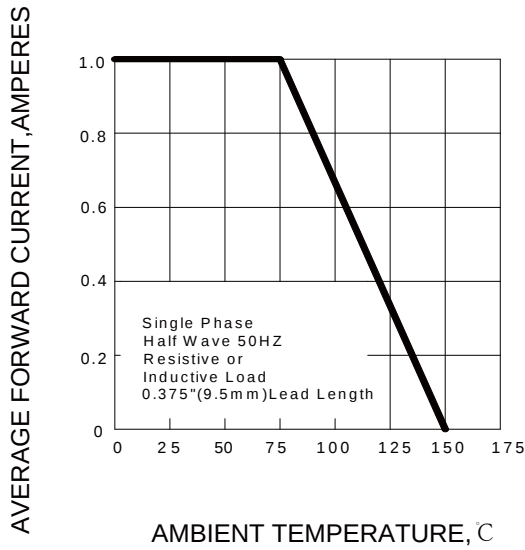


FIG.2 – TYPICAL FORWARD CHARACTERISTIC

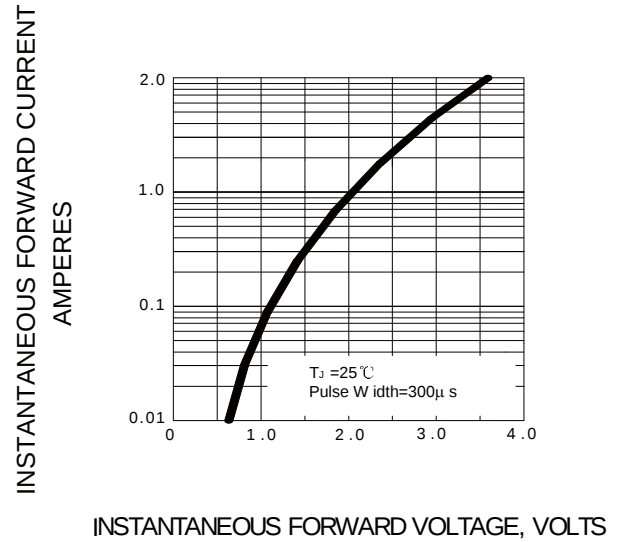


FIG.3 –PEAK FORWARD SURGE CURRENT

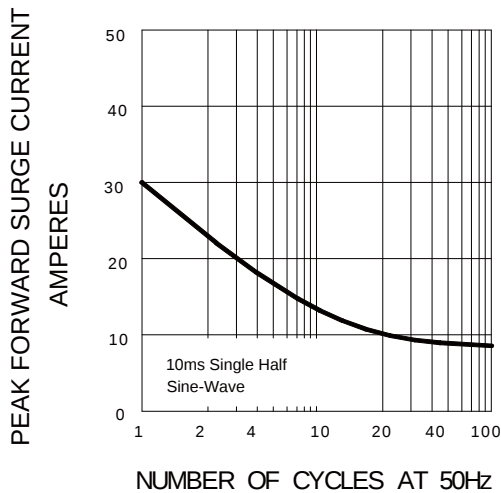


FIG.4 – TYPICAL JUNCTION CAPACITANCE

